

APT33GF120B2RDQ2G

APT33GF120B2RDQ2G Information



For Reference Only

Part Number APT33GF120B2RDQ2G Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

Description IGBT 1200V 64A 357W TMAX

Package TO-247-3 Variant

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APT33GF120B2RDQ2G Specifications

Manufacturer Part Number	APT33GF120B2RDQ2G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3 Variant
Series	-
IGBT Type	NPT
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	64A
Current - Collector Pulsed (Icm)	75A
Vce(on) (Max) @ Vge, Ic	3V @ 15V, 25A
Power - Max	357W
Switching Energy	1.315μJ (on), 1.515μJ (off)
Input Type	Standard
Gate Charge	170nC
Td (on/off) @ 25°C	14ns/185ns
Test Condition	800V, 25A, 4.3 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3 Variant
Supplier Device Package	-
	Report errors?

APT33GF120B2RDQ2G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APT33GF120B2RDQ2G Payment Methods





















APT33GF120B2RDQ2G Shipping Methods













If you have any question about APT33GF120B2RDQ2G, please do not hesitate to contact us!

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